Low Skew, 1-to-8

DIFFERENTIAL-TO-3.3V LVPECL/ECL FANOUT BUFFER

GENERAL DESCRIPTION



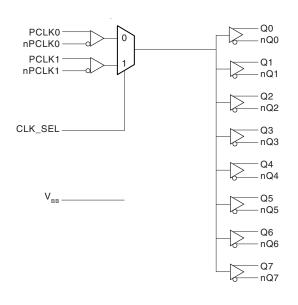
The ICS853310 is a low skew, high performance 1-to-8 Differential-to-3.3V LVPECL/ECL Fanout Buffer and a member of the HiPerClockS™family of High Performance Clock Solutions from ICS. The PCLKx, nPCLKx

pairs can accept LVPECL, LVDS, CML and SSTL differential input levels. The ICS853310 is characterized to operate from a 3.3V power supply. Guaranteed output and part-to-part skew characteristics make the ICS853310 ideal for those clock distribution applications demanding well defined performance and repeatability.

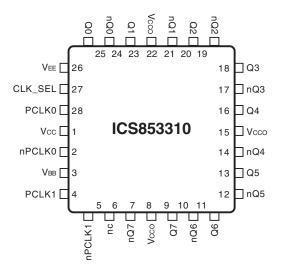
FEATURES

- 8 differential 3.3V LVPECL / ECL outputs
- · 2 selectable differential LVPECL input pairs
- PCLKx, nPCLKx pairs can accept the following differential input levels: LVPECL, LVDS, CML, SSTL
- Output frequency: >2GHz (typical)
- Translates any single ended input signal to 3.3V LVPECL levels with resistor bias on nPCLKx input
- Output skew: 50ps (maximum)
- Part-to-part skew: 200ps (maximum)
- Propagation delay: 900ps (maximum)
- LVPECL mode operating voltage supply range: $V_{CC} = 3V$ to 3.8V, $V_{EE} = 0V$
- ECL mode operating voltage supply range: $V_{CC} = 0V$, $V_{EE} = -3V$ to -3.8V
- -40°C to 85°C ambient operating temperature
- Pin compatible with MC100LVE310

BLOCK DIAGRAM



PIN ASSIGNMENT



28-Lead PLCC 11.6mm x 11.4mm x 4.1mm package body V Package Top View

TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	/ре	Description
1	V _{cc}	Power		Core supply pin.
2	nPCLK0	Input	Pullup/ Pulldown	Inverting differential LVPECL clock input. V _{cc} /2.
3	$V_{_{\mathrm{BB}}}$	Output		Bias voltage.
4	PCLK1	Input	Pulldown	Non-inverting differential LVPECL clock input.
5	nPCLK1	Input	Pullup/ Pulldown	Inverting differential LVPECL clock input. V _{cc} /2.
6	nc	Unused		No connect.
7, 9	nQ7, Q7	Output		Differential output pair. LVPECL interface levels.
8, 15, 22	V _{cco}	Power		Output supply pins.
10, 11	nQ6, Q6	Output		Differential output pair. LVPECL interface levels.
12, 13	nQ5, Q5	Output		Differential output pair. LVPECL interface levels.
14, 16	nQ4, Q4	Output		Differential output pair. LVPECL interface levels.
17, 18	nQ3, Q3	Output		Differential output pair. LVPECL interface levels.
19, 20	nQ2, Q2	Output		Differential output pair. LVPECL interface levels.
21, 23	nQ1, Q1	Output		Differential output pair. LVPECL interface levels.
24, 25	nQ0, Q0	Output		Differential output pair. LVPECL interface levels.
26	V _{EE}	Power		Negative supply pin.
27	CLK_SEL	Input	Pulldown	Clock Select input. When HIGH, selects PCLK1, nPCLK1 inputs. When LOW, selects PCLK0, nPCLK0 inputs. LVCMOS / LVTTL interface levels.
28	PCLK0	Input	Pulldown	Non-inverting differential LVPECL clock input.



ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{cc} Negative Supply Voltage, V_{EE} -4.6V (LVECL mode, $V_{CC} = 0$) Inputs, V, (LVPECL mode) -0.5V to $V_{CC} + 0.5 V$

Inputs, V, (LVECL mode) 0.5V to V_{EE} - 0.5V

Outputs, I_o

Continuous Current 50mA Surge Current 100mA V_{BB} Sink/Source, I_{BB} $\pm 0.5 mA$ Operating Temperature Range, TA -40°C to +85°C Storage Temperature, T_{STG} -65°C to 150°C

Wave Solder, T_{SOL} 265°C

4.6V (LVPECL mode, $V_{\text{EE}} = 0$) | **NOTE:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the DC Characteristics or AC Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 2A. LVPECL Power Supply DC Characteristics, $V_{CC} = 3V$ to 3.8V; $V_{EE} = 0V$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{cc}	Core Supply Voltage		3.0	3.3	3.8	V
V _{cco}	Output Supply Voltage		3.0	3.3	3.8	V
I _{EE}	Power Supply Current				70	mA

Table 2B. LVPECL DC Characteristics, $V_{CC} = 3.3V$; $V_{FF} = 0V$

Symbol	Parameter		-40°C			25°C				Unit-		
Symbol			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	s
V _{OH}	Output High	n Voltage; NOTE 1	2.175	2.275	2.38	2.225	2.295	2.37	2.295	2.22	2.365	V
V _{OL}	Output Low	Voltage; NOTE 1	1.405	1.545	1.68	1.425	1.52	1.615	1.44	1.535	1.63	V
V _{IH}	Input High Voltage (Single-Ended)		2.075		2.36	2.075		2.36	2.075			V
V _{IL}	Input Low Voltage (Single-Ended)		1.43		1.765	1.43		1.765	1.43		1.765	V
V _{BB}	Output Voltage Reference; NOTE 2		1.86		1.98	1.86		1.98	1.86		1.98	mV
V _{PP}	Peak-to-Peak Input Voltage		500		1000	500		1000	500		1000	mV
V _{CMR}	Input High Voltage Common Mode Range; NOTE 3		1.8		2.9	1.8		2.9	1.8		2.9	٧
I _{IH}	Input High Current	PCLK0, PCLK1 nPCLK0, nPCLK1 CLK_SEL			150			150			150	μA
I _{IL}	Input Low Current	PCLK0, PCLK1, nPCLK0, nPCLK1 CLK_SEL	-150			-150			-150			μA

NOTE 1: Input and output parameters vary 1:1 with $\rm V_{\rm CC}$. $\rm V_{\rm EE}$ can vary ±0.3V.

Please refer to Parameter Measurement Information, "Output Load AC Test Circuit".

NOTE 2: Outputs terminated with 50 Ω to V_{CCO} - 2V. NOTE 3: V_{CMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}. V_{CMR} is defined as the range within which the V_{IH} level may vary, with the device still meeting the propagation delay specification. The V_{IL} level must be such that the peak-to-peak voltage is less than 1V and greater than or equal to V_{PP}(min).

Low Skew, 1-TO-8

DIFFERENTIAL-TO-3.3V LVPECL/ECL FANOUT BUFFER

Table 2C. LVECL Power Supply DC Characteristics, $V_{CC} = 0V$; $V_{EE} = -3.3V \pm 0.3V$

Symbol	Parameter	Test Conditions	ons Minimum Typical		Maximum	Units
V _{EE}	Supply Voltage		-3.0	-3.3	-3.8	V
I _{EE}	Power Supply Current				70	mA

Table 2D. ECL DC Characteristics, $V_{CC} = 0V$; $V_{EE} = -3.3V \pm 0.3V$

Cumbal	Parameter			-40°C			25°C			85°C			
Symbol	Parameter	Parameter		Тур	Max	Min	Тур	Max	Min	Тур	Max	Units	
V _{OH}	Output High	n Voltage	-1.125	-1.025	-0.92	-1.075	-1.005	-0.93	-1.005	-1.08	-0.935	V	
V _{OL}	Output Low	Voltage	-1.895	-1.755	-1.62	-1.875	-1.78	-1.685	-1.86	-1.765	-1.67	V	
V _{IH}	Input High \	Voltage (Single-Ended)	-1.225		-0.94	-1.225		-0.94	-1.225			V	
V _{IL}	Input Low Voltage (Single-Ended)		-1.87		-1.535	-1.87		-1.535	-1.87		-1.535	V	
V _{BB}	Output Voltage Reference; NOTE 1		-1.44		-1.32	-1.44		-1.32	-1.44		-1.32	mV	
V _{PP}	Peak-to-Peak Input Voltage		500		1000	500		1000	500		1000	mV	
V _{CMR}	Input High Voltage Common Mode Range; NOTE 2		1.5		-0.4	1.5		-0.4	1.5		-0.4	V	
I _{IH}	Input High Current	PCLK0, PCLK1, nPCLK0, nPCLK1 CLK_SEL			150			150			150	μΑ	
IIL	Input Low Current	PCLK0, PCLK1, nPCLK0, nPCLK1 CLK_SEL	-150			-150			-150			μΑ	

NOTE 1: Outputs terminated with 50Ω to V_{CCO} - 2V. NOTE 2: V_{CMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} . V_{CMR} is defined as the range within which the V_{IH} level may vary, with the device still meeting the propagation delay specification. The V_{IL} level must be such that the peak-to-peak voltage is less than 1V and greater than or equal to $V_{PP}(min)$.

Table 3. AC Characteristics, $V_{CC} = 3.3V$; $V_{EE} = 0V$ or $V_{CC} = 0V$; $V_{EE} = -3.3V$

Cumbal	Developmentary		-40°C			25°C			85°C			Linita
Symbol	Parameter			Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
f _{MAX}	Output Frequency			>2			>2			>2		GHz
$t_{\scriptscriptstyle{\mathrm{PD}}}$	Propagation Delay; NOTE 1		700		900	750		950	775		975	ps
tsk(o)	Output Skew; NOTE 2, 4				75			50			50	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4				250			200			200	ps
t _R /t _F	Output Rise/Fall Time	20% to 80%	100		400	100		400	100		400	ps

 V_{EE} can very \pm 0.3V.

All parameters measured at $f \le 1.2$ GHz unless noted otherwise.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

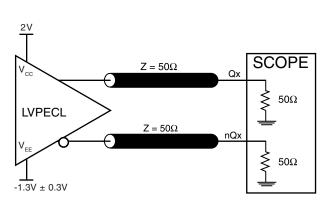
NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

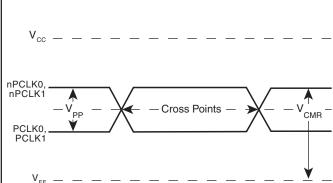
Measured at the output differential cross points.

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

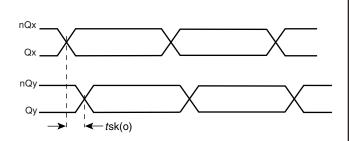
NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

PARAMETER MEASUREMENT INFORMATION

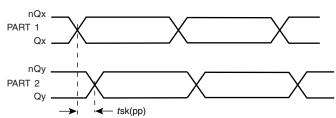




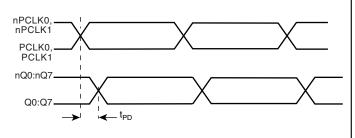
OUTPUT LOAD AC TEST CIRCUIT



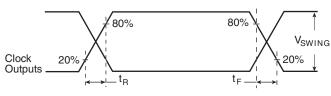
DIFFERENTIAL INPUT LEVEL



OUTPUT SKEW



PART-TO-PART SKEW



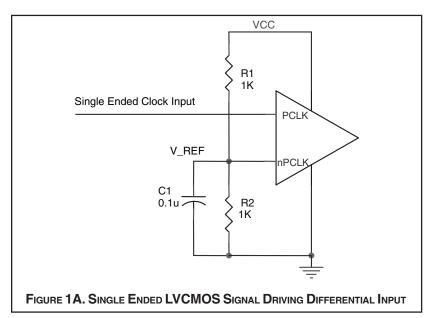
PROPAGATION DELAY

APPLICATION INFORMATION

WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LVCMOS LEVELS

Figure 1A shows an example of the differential input that can be wired to accept single ended LVCMOS levels. The reference voltage level $V_{\tiny BB}$ generated from the device is connected to

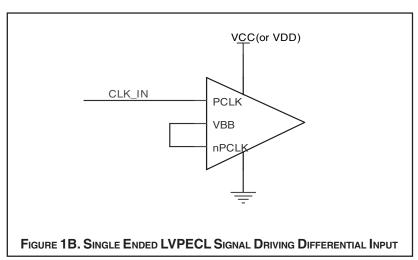
the negative input. The C1 capacitor should be located as close as possible to the input pin.



WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LVPECL LEVELS

Figure 1B shows an example of the differential input that can be wired to accept single ended LVPECL levels. The reference ${\bf P}$

voltage level $V_{\mbox{\tiny BB}}$ generated from the device is connected to the negative input.



Low Skew, 1-TO-8

DIFFERENTIAL-TO-3.3V LVPECL/ECL FANOUT BUFFER

TERMINATION FOR LVPECL OUTPUTS

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

FOUT and nFOUT are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive

 $Z_0 = 50\Omega$ $Z_0 = 50\Omega$ 50Ω ₹ 50Ω

FIGURE 2A. LVPECL OUTPUT TERMINATION

 50Ω transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. Figures 2A and 2B show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

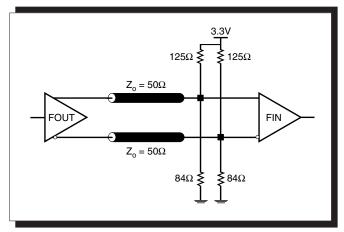


FIGURE 2B. LVPECL OUTPUT TERMINATION

LVPECL CLOCK INPUT INTERFACE

The PCLK /nPCLK accepts LVPECL, CML, SSTL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. *Figures 3A to 3F* show interface examples for the HiPerClockS PCLK/nPCLK input driven by the most common driver types. The input interfaces suggested

here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

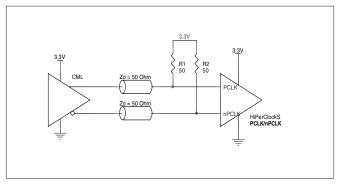


FIGURE 3A. HIPERCLOCKS PCLK/nPCLK INPUT DRIVEN BY AN OPEN COLLECTOR CML DRIVER

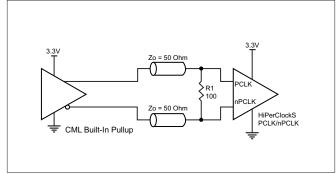


FIGURE 3B. HIPERCLOCKS PCLK/nPCLK INPUT DRIVEN
BY A BUILT-IN PULLUP CML DRIVER

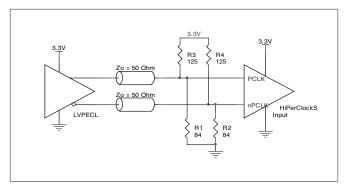


FIGURE 3C. HIPERCLOCKS PCLK/nPCLK INPUT DRIVEN
BY A 3.3V LVPECL DRIVER

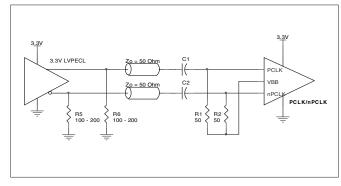


FIGURE 3D. HIPERCLOCKS PCLK/nPCLK INPUT DRIVEN
BY A 3.3V LVPECL DRIVER WITH AC COUPLE

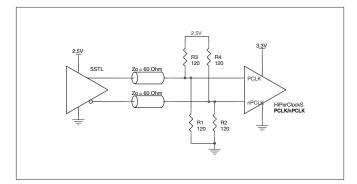


FIGURE 3E. HIPERCLOCKS PCLK/nPCLK INPUT DRIVEN BY AN SSTL DRIVER

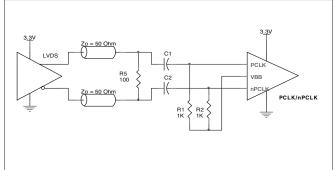


FIGURE 3F. HIPERCLOCKS PCLK/nPCLK INPUT DRIVEN BY A 3.3V LVDS DRIVER

SCHEMATIC EXAMPLE

Figure 4A shows a schematic example of the ICS853310. In this example, the PCLK0/nPCLK0 input is selected. The decoupling

capacitors should be physically located near the power pin. For ICS853310, the unused outputs can be left floating.

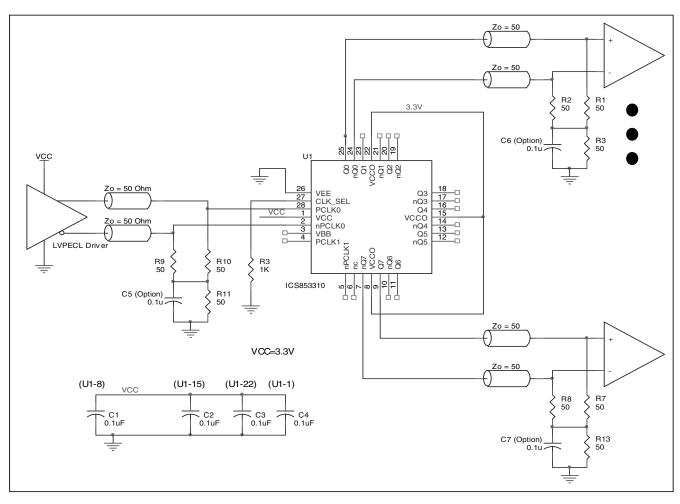


FIGURE 4A. ICS853310 LVPECL CLOCK OUTPUT BUFFER SCHEMATIC EXAMPLE

POWER, GROUND AND BYPASS CAPACITOR

This section provides a layout guide related to power, ground and placement of bypass capacitors for a high-speed digital IC. This layout guide is a general recommendation. The actual board design will depend on the component types being used, the board density and cost constraints. This description assumes that the board has clean power and ground planes. The goal is to minimize the ESR between the clean power/ground plane and the IC power/ground pin.

A low ESR bypass capacitor should be used on each power pin. The value of bypass capacitors ranges from 0.01uF to 0.1uF. The bypass capacitors should be located as close to the power

pin as possible. It is preferable to locate the bypass capacitor on the same side as the IC. *Figure 4B* shows suggested capacitor placement. Placing the bypass capacitor on the same side as the IC allows the capacitor to have direct contact with the IC power pin. This can avoid any vias between the bypass capacitor and the IC power pins.

The vias should be placed at the Power/Ground pads. There should be a minimum of one via per pin. Increasing the number of vias from the Power/Ground pads to Power/Ground planes can improve the conductivity.

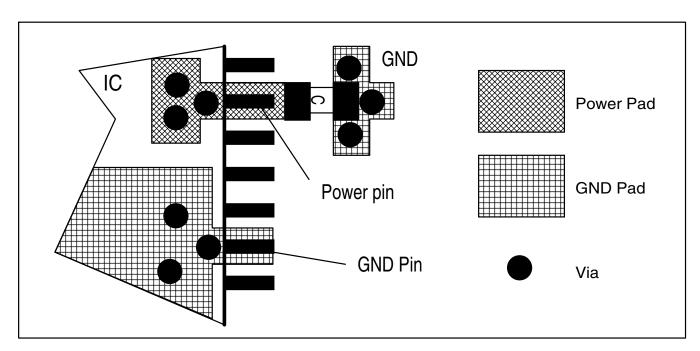


FIGURE 4B. RECOMMENDED LAYOUT OF BYPASS CAPACITOR PLACEMENT

Low Skew, 1-to-8 Differential-to-3.3V LVPECL/ECL Fanout Buffer

POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the ICS853310. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS853310 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.8V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = V_{CC_MAX} * I_{EE_MAX} = 3.8V * 70mA = 266mW
- Power (outputs)_{MAX} = 30.94mW/Loaded Output pair
 If all outputs are loaded, the total power is 8 * 30.94mW = 247.5mW

Total Power MAX (3.8V, with all outputs switching) = 266mW + 247.5mW = 513.5mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS TM devices is 125 $^{\circ}$ C.

The equation for Tj is as follows: Tj = θ_{JA} * Pd_total + T_A

Tj = Junction Temperature

 θ_{IA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

 T_{Δ} = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance $\theta_{\rm JA}$ must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 31.1°C/W per Table 4 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

 $85^{\circ}\text{C} + 0.514\text{W} * 31.1^{\circ}\text{C/W} = 101^{\circ}\text{C}$. This is well below the limit of 125°C .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

Table 4. Thermal Resistance θ_{JA} for 28-pin PLCC, Forced Convection

$\theta_{_{JA}}$ by Velocity (Linear Feet per Minute)

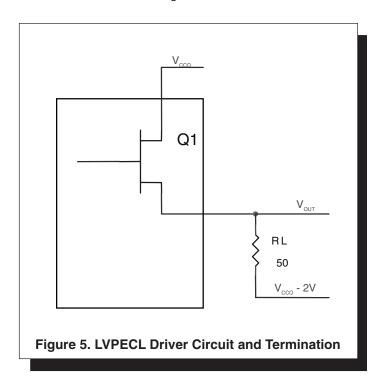
 0
 200
 500

 Multi-Layer PCB, JEDEC Standard Test Boards
 37.8°C/W
 31.1°C/W
 28.3°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

3. Calculations and Equations.

LVPECL output driver circuit and termination are shown in Figure 5.



To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of V $_{\text{CCO}}$ - 2V.

• For logic high,
$$V_{OUT} = V_{OH_MAX} = V_{CCO_MAX} - 0.935V$$

$$(V_{CCO_MAX} - V_{OH_MAX}) = 0.935V$$

• For logic low,
$$V_{OUT} = V_{OL_MAX} = V_{CCO_MAX} - 1.67V$$

$$(V_{CCO_MAX} - V_{OL_MAX}) = 1.67V$$

Pd_H is power dissipation when the output drives high.
Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CCO_MAX} - 2V))/R_{L}] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - (V_{CCO_MAX} - V_{OH_MAX}))/R_{L}] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - 0.935V)/50\Omega] * 0.935V = 19.92mW$$

$$Pd_L = [(V_{OL_MAX} - (V_{CCO_MAX} - 2V))/R_{L}] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - (V_{CCO_MAX} - V_{OL_MAX}))/R_{L}] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - 1.67V)/50\Omega] * 1.67V = 11.02mW$$

Total Power Dissipation per output pair = Pd_H + Pd_L = 30.94mW

ICS853310

Low Skew, 1-to-8 DIFFERENTIAL-TO-3.3V LVPECL/ECL FANOUT BUFFER

RELIABILITY INFORMATION

Table 5. $\boldsymbol{\theta}_{\text{JA}} \text{vs. Air Flow Table for 28 Lead PLCC}$

 $\theta_{_{JA}}$ by Velocity (Linear Feet per Minute)

200

500

Multi-Layer PCB, JEDEC Standard Test Boards

37.8°C/W

31.1°C/W

28.3°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for ICS853310 is: 462

PACKAGE OUTLINE - V SUFFIX FOR 28 LEAD PLCC

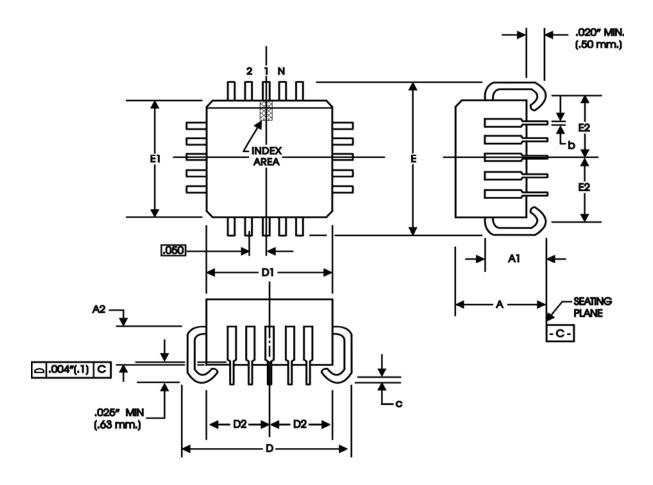


TABLE 6. PACKAGE DIMENSIONS

JEDEC VARIATION ALL DIMENSIONS IN MILLIMETERS							
SYMBOL	MINIMUM	MAXIMUM					
N	2	8					
Α	4.19	4.57					
A1	2.29	3.05					
A2	1.57	2.11					
b	0.33	0.53					
С	0.19	0.32					
D	12.32	12.57					
D1	11.43	11.58					
D2	4.85	5.56					
E	12.32	12.57					
E1	11.43	11.58					
E2	4.85	5.56					

Reference Document: JEDEC Publication 95, MS-018



ICS853310

Low Skew, 1-to-8 DIFFERENTIAL-TO-3.3V LVPECL/ECL FANOUT BUFFER

TABLE 7. ORDERING INFORMATION

Part/Order Number	Marking	Package	Count	Temperature	
ICS853310AV	ICS853310AV	28 Lead PLCC	38 per Tube	-40°C to 85°C	
ICS853310AVT	ICS853310AV	28 Lead PLCC on Tape and Reel	500	-40°C to 85°C	

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